

1

MOSFET Maximum Ratings T _C = 25°C unless otherwise noted	
--	--

Symbol	Parameter		Ratings	Units
V _{DSS}	Drain to Source Voltage		-40	V
V _{GS}	Gate to Source Voltage		±20	V
	Drain Current Continuous (T _C < 130°C, V _{GS} = 10V)		-14	•
ID	Pulsed		See Figure 4	— A
E _{AS}	Single Pulse Avalanche Energe	(Note 1)	84	mJ
D	Power Dissipation		50	W
P _D	Dreate above 25°C		0.34	W/ºC
T _J , T _{STG}	Operating and Storage Temperature		-55 to +175	°C

Thermal Characteristics

$R_{ ext{ heta}JC}$	Maximum Thermal Resistance Junction to Case	3	°C/W
R_{\thetaJA}	Maximum Thermal Resistance Junction to Ambient TO-252, 1in ² copper pad area	40	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD4243	FDD4243-F085	TO252	13"	12mm	2500 units
Note:					

 A suffix as "...F085P" has been temporarily introduced in order to manage a double source strategy as ON Semiconductor has officially announced in Aug 2014.

Electrical Characteristics T_J = 25°C unless otherwise noted

	-					
Symbo	I Parameter	Test Conditions	Min	Тур	Max	Units
						-

Off Characteristics

BV _{DSS}	Drain to Source Breakdown Voltage	I_{D} = -250 μ A, V_{GS} = 0V	-40	-	-	V
$\Delta BV_{DSS} \Delta T_J$	Breakdown Voltage Temperature Coefficient	ID = -250µA, referenced to 25°C	-	-32	-	mV/°C
1	Zero Gate Voltage Drain Current	V _{DS} = -32V	-	-	-1	μA
DSS	Zero Gale Voltage Drain Gurrent	$T_{\rm J} = 125^{\rm o}{\rm C}$	-	-	-100	μΛ
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20V$	-	-	±100	nA

On Characteristics

V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = -250 \mu A$	-1.4	-1.6	-3.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	ID = -250μ A, referenced to 25° C	-	4.7	-	mV/°C
		I _D = -6.7A, V _{GS} = -10V	-	36	44	
r	Drain to Source On Resistance	I _D = -5.5A, V _{GS} = -4.5V	-	48	64	mΩ
r _{DS(on)}		I _D = -6.7A, V _{GS} = -10V, T _J = 150 ^o C	-	57	70	11152
9 _{FS}	Forward Transconductance	$I_{\rm D} = -6.7$ A, $V_{\rm DS} = -5$ V,	-	23	-	S

Dynamic Characteristics

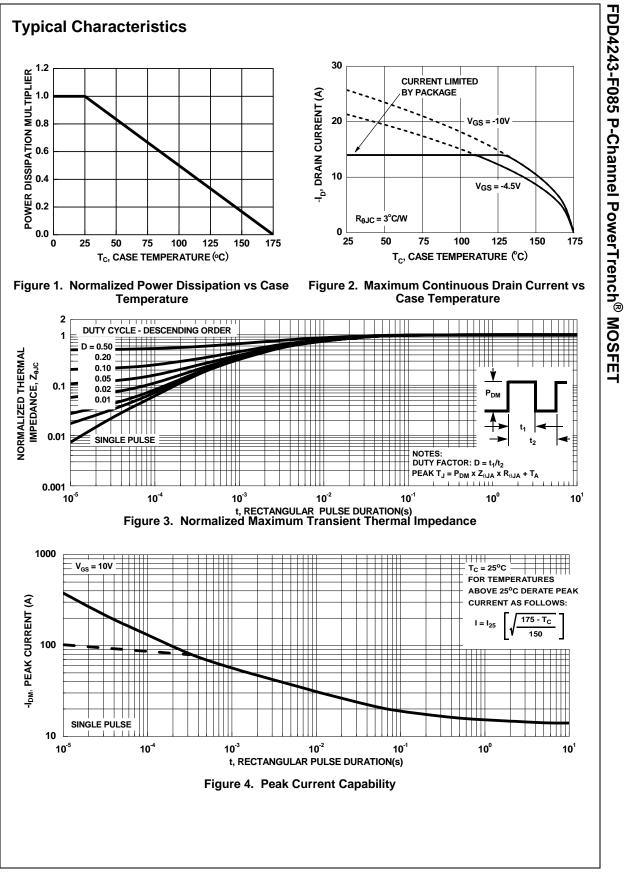
Ciss	Input Capacitance	V 00V/V 0V/	-	1165	1550	pF
Coss	Output Capacitance	−V _{DS} = -20V, V _{GS} = 0V, _f = 1MHz	-	165	220	pF
C _{rss}	Reverse Transfer Capacitance		-	90	135	pF
R _G	Gate Resistance	f = 1MHz	-	4	-	Ω
Q _{g(TOT)}	Total Gate Charge		-	21	29	nC
Q _{gs}	Gate to Source Gate Charge	$V_{DD} = -20V, V_{GS} = -10V$	-	3.4	-	nC
Q _{gd}	Gate to Drain "Miller" Charge	$I_{\rm D}$ = -6.7A	-	4	-	nC

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Switch	ing Characteristics					
t _{d(on)}	Turn-On Delay Time		-	6	12	ns
t _r	Rise Time	V_{DD} = -20V, I _D = -6.7A V_{GS} = -10V, R _{GEN} = 6 Ω	-	15	26	ns
t _{d(off)}	Turn-Off Delay Time		-	22	35	ns
t _f	Fall Time		-	7	14	ns
Drain-So	Source to Drain Diode Voltage	I _{SD} = -6.7A, V _{GS} =0V	-	-0.86	-1.2	V
t _{rr}	Reverse Recovery Time	1 = 6.70 dt (dt = 1000)/000	-	29	43	ns
-11		—— I _{SD} = -6.7A, dI _{SD} /dt = 100A/μs		-		

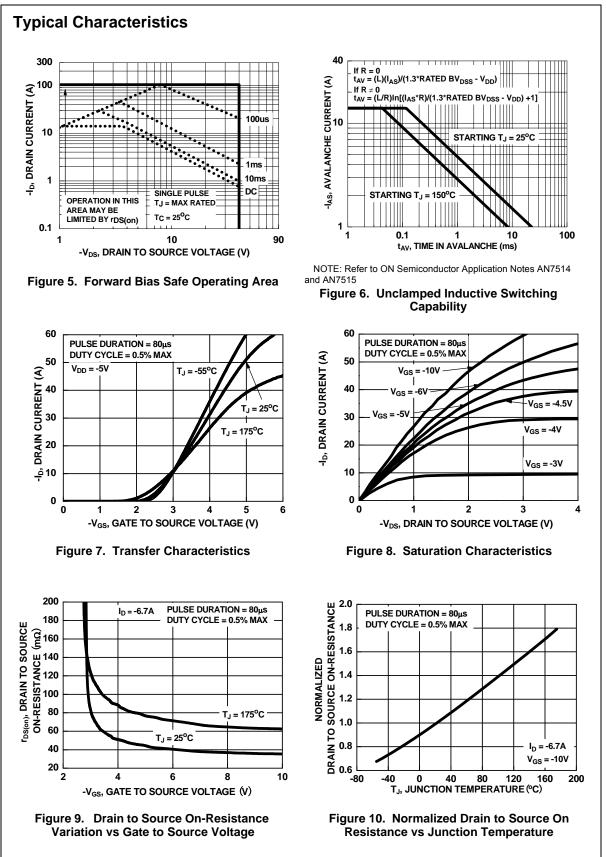
Starting T_J= 25°C, L = 3mH, I_{AS}= 7.5A, V_{GS}= 10V, V_{DD}= 40V during the inductor charging time and 0V during the time in avalanche.

This product has been designed to meet the extreme test conditions and environment demanded by the automotive industry. For a copy of the requirements, see AEC Q101 at: http://www.aecouncil.com/ All ON Semiconductor products are manufactured, assembled and tested under ISO9000 and QS9000 quality systems

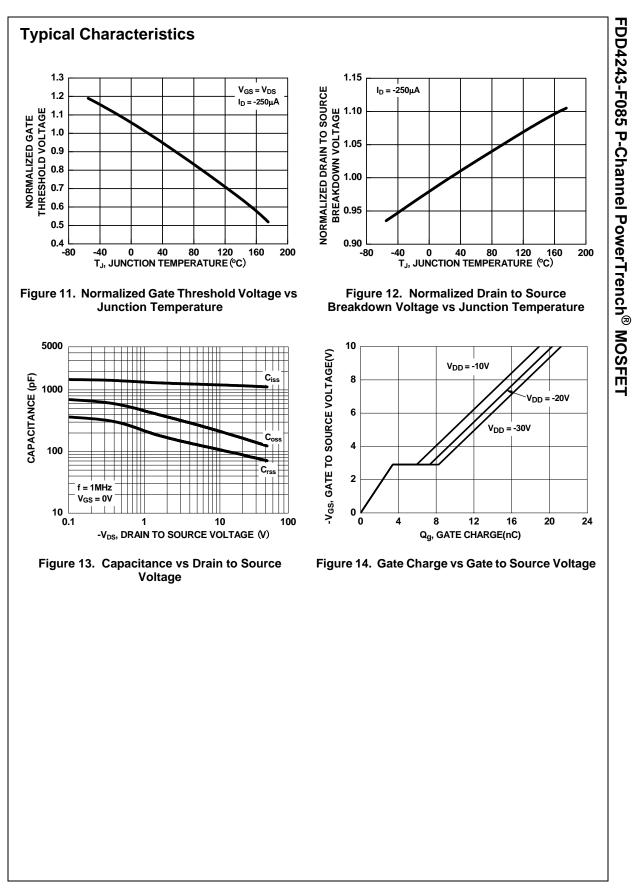
certification.



www.onsemi.com 4



FDD4243-F085 P-Channel PowerTrench[®] MOSFET



ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights or others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor haves, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such uninten

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81–3–5817–1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ON Semiconductor: FDD4243_F085P FDD4243-F085P